

# High efficiency thermally activated delayed fluorescence and its application for OLED

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## 1. Introduction

In organic light emitting diodes (OLEDs), exciton generation by current results in 25% of singlet excitons ( $S_1$ ) and 75% of triplet excitons ( $T_1$ ), respectively. Therefore, in general, OLEDs that use fluorescence materials can produce only 25% singlet excitons. To improve efficiency of exciton production at a  $S_1$  level, we employed the mechanism of thermally activated delayed fluorescence (TADF)<sup>1</sup> for OLEDs<sup>2</sup>. To realize high TADF efficiency, we need materials that have a small energy gap between  $S_1$  and  $T_1$  levels. In this study, we developed a novel triazin derivative (PIC-TRZ) having a very small energy gap between  $S_1$  and  $T_1$  excited states,  $\Delta E_{1-3}$ , that realizes efficient up-conversion of triplet excitons into a singlet state.

## 2. Result and Discussion

In this study, we fabricated thin films of 6wt%-PIC-TRZ:host for PL analysis and OLEDs with PIC-TRZ:host as an emitter layer. The fluorescence and phosphorescence spectra of PIC-TRZ are shown in Fig. 1. We observed the overlap between the fluorescence and phosphorescence ( $T=5$  K) spectra with their 0-0 transition peaks at 466 nm ( $S_1=2.66$  eV) and 483 nm ( $S_1=2.55$  eV), respectively, indicating the realization of very small  $\Delta E_{1-3}=0.11$  eV. The PL quantum efficiency increased with increasing the  $T_1$  level of host materials and the highest PL quantum efficiency of 39% was obtained in a 6wt%-PIC-TRZ: 9,9'-(1,3-phenylene)bis-9H-carbazole (m-CP) film. The film showed intense delayed fluorescence with the same spectrum of the prompt fluorescence (Fig. 2), although the neat PIC-TRZ film resulted in no appreciable TADF. This result shows that suppression of concentration quenching and energy transfer between guest and host  $T_1$  levels is crucial to improve TADF efficiency. We also fabricated an OLED device using 6wt%-PIC-TRZ: m-CP as an emitting layer. The OLED showed external EL quantum efficiency of 5.1% (Fig. 3). When we use a conventional fluorescence material having  $\Phi_{PL}=39\%$  as an emitter, the theoretical  $\Phi_{EL(ext)}$  resulted in the small value of 2%. Thus, the OLED is surely exceeding the limitation of singlet exciton production rule, indicating significant contribution of TADF.

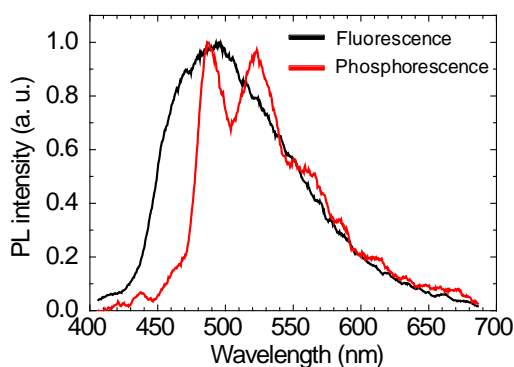


Fig. 1 Fluorescence and phosphorescence spectra of PIC-TRZ film

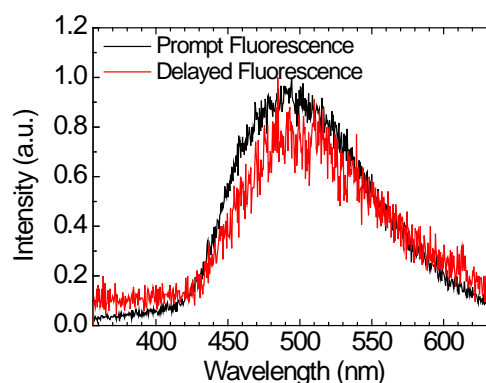
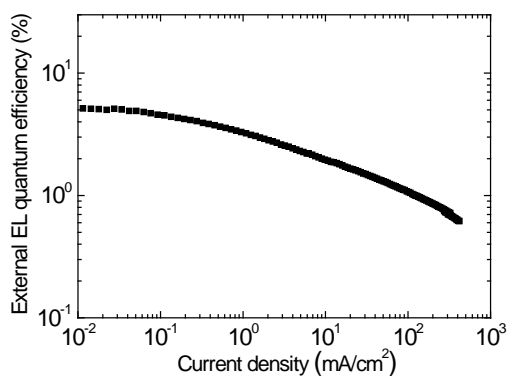


Fig. 2 Fluorescence and delayed fluorescence spectra of PIC-TRZ: m-CP film



**Fig. 3** EQE-current density characteristics in ITO/  
 $\alpha$ -NPD (40 nm)/m-CP (10 nm)/6wt%-PIC  
-TRZ:m-CP (20 nm)/BP4mPy (40 nm)/ LiF  
(0.8 nm)/Al (100 nm)

### 3. References

- [1] Valeur, B., Molecular Fluorescence, Wiley-VCH, Weinheim, 2002, p.41
- [2] A. Endo, M. Ogasawara, A. Takahashi, D. Yokoyama, Y. Kato and C. Adachi, *Adv. Mater.*, **21**, 4802 (2009)

### 4. Acknowledgement

This work was supported in part by Funding Program for World-Leading Innovative R&D on Science and Technology (FIRST) and the Global COE (Centers of Excellence) Program “Science for Future Molecular Systems” from the Ministry of Education, Culture, Sports, Science and Technology (MEXT)